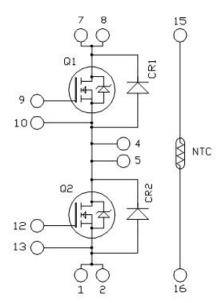
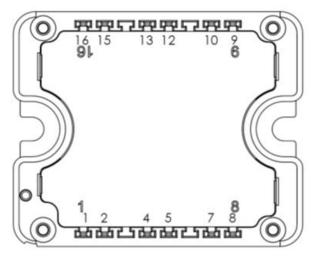


Phase Leg SiC MOSFET Power Module

Product Overview

The MSCSM170AM45CT1AG device is a phase leg 1700 V, 64 A silicon carbide (SiC) MOSFET power module.





Note: Pins 1/2, 4/5, and 7/8 must be shorted together. All ratings at $T_J = 25$ °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are key features of the MSCSM170AM45CT1AG device:

- SiC Power MOSFET
 - High speed switching
 - Low R_{DS(on)}
 - Ultra low loss
- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on VF
- Very low stray inductance
- Kelvin source for easy drive
- Internal thermistor for temperature monitoring
- Aluminum nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM170AM45CT1AG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- · Low junction-to-case thermal resistance
- · Solderable terminals for power and signal for easy mounting of PCB
- Low profile
- RoHS Compliant

Application

The MSCSM170AM45CT1AG device is designed for the following applications:

- · Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM170AM45CT1AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings per SiC MOSFET of the MSCSM170AM45CT1AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V _{DSS}	Drain-Source voltage		1700	V
I _D	Continuous drain current	T _C = 25 °C	64	A
		T _C = 80 °C	51	
I _{DM}	Pulsed drain current		130	
V _{GS}	Gate-source voltage		-10/23	V
R _{DS(on)}	Drain-source ON resistance		45	mΩ
P _D	Power dissipation	T _C = 25 °C	319	W

The following table lists the electrical characteristics per SiC MOSFET of the MSCSM170AM45CT1AG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0 V; V _{DS} = 1700 V	V	_	10	100	μA
R _{DS(on)}	Drain-Source on	V _{GS} = 20 V	T _J = 25 °C	_	35	45	mΩ
	resistance	I _D = 30 A	T _J = 175 °C	_	62		
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}; I_D = 2.5 \text{ mA}$		1.8	3.2		V
I _{GSS}	Gate–Source leakage current	V_{GS} = 20 V; V_{DS} = 0 V				150	nA

Table 1-2. Electrical Characteristics

Electrical Specifications

The following table lists the dynamic characteristics per SiC MOSFET of the MSCSM170AM45CT1AG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
C _{iss}	Input capacitance	V _{GS} = 0 V		—	3300	—	pF
C _{oss}	Output capacitance	V _{DS} = 1000 V		—	150		
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	10	—	
Qg	Total gate charge	V_{GS} = -5 V/20 V		-	178	_	nC
Q _{gs}	Gate-source charge	V _{Bus} = 850 V		_	49	_	
Q _{gd}	Gate-drain charge	I _D = 30 A		—	27	—	
T _{d(on)}	Turn-on delay time	T _J = 150 °C		_	24	_	ns
Tr	Rise time	V _{GS} = -5 V/20 V		—	17	—	
T _{d(off)}	Turn-off delay time	V _{Bus} = 900 V		_	35	_	
T _f	Fall time	$I_D = 50 \text{ A}$ $R_{G(on)} = 4.7 \Omega$ $R_{G(off)} = 2.7 \Omega$			19	_	
Eon	Turn-on energy	V _{GS} = -5 V/20 V	T _J = 150 °C	_	1.1	_	mJ
E _{off}	Turn-off energy	$V_{Bus} = 900 V$ $I_D = 50 A$ $R_{G(on)} = 4.7 Ω$ $R_{G(off)} = 2.7 Ω$	T _J = 150 °C	—	0.16	—	
R _{Gint}	Internal gate resistance	9		-	0.85	_	Ω
R _{thJC}	Junction-to-case therm	al resistance		—	—	0.47	°C/W

Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics per SiC MOSFET of the MSCSM170AM45CT1AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Мах	Unit
V_{SD}	Diode forward voltage	V _{GS} = 0 V; I _{SD} = 30 A	_	3.7	—	V
		V_{GS} = -5 V; I_{SD} = 30 A	_	3.9	—	
t _{rr}	Reverse recovery time	I_{SD} = 30 A; V_{GS} = -5 V		27	_	ns
Q _{rr}	Reverse recovery charge	V _R = 900 V; di _F /dt = 1000 A/µs		650	_	nC
I _{rr}	Reverse recovery current			46	_	А

1.2 SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics per SiC diode of MSCSM170AM45CT1AG device.

Table 1-5.	SiC Schottky Dic	ode Ratings and	Characteristics
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Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Peak repetitive reverse vol	age		_	—	1700	V
I _{RRM}	Reverse leakage current	V _R = 1700 V	T _J = 25 °C	_	10	200	μA
			T _J = 175 °C	_	150	—	
I _F	DC forward current	—	T _C = 125 °C	_	30	—	A
V _F	Diode forward voltage	I _F = 30 A	T _J = 25 °C	_	1.5	1.8	V
			T _J = 175 °C	_	2.3	—	
Q _C	Total capacitive charge	V _R = 900 V		_	230	—	nC
С	Total capacitance	f = 1 MHz, V _R = 6	00 V	_	167	—	pF
		f = 1 MHz, V _R = 9	000 V	_	138	—	
R _{thJC}	Junction-to-case thermal re	esistance		_	_	0.52	°C/W

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM170AM45CT1AG device.

Table 1-6. Thermal and Package Characteristics

Symbol	Characteristics			Min	Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to c	ase t =1 min, 5	50 Hz/60 Hz	4000		V
TJ	Operating junction temperature range			-40	175	°C
T _{JOP}	Recommended junction temperature un	der switching o	conditions	-40	T _{Jmax} – 25	
T _{STG}	Storage temperature range			-40	125	
T _C	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package weight	· · · · ·			80	g

Electrical Specifications

The following table lists the temperature sensor NTC of the MSCSM170AM45CT1AG device.

Table 1-7. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25 °C	—	_	50	—	kΩ
$\Delta R_{25}/R_{25}$	—	—	_	5		%
B _{25/85}	T ₂₅ = 298.15 K	—		3952	_	К
ΔΒ/Β	—	T _C = 100 °C		4	_	%

 $R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$ T: Thermistor temperature R_T: Thermistor value at T

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.4 Typical SiC MOSFET Performance Curve

This section shows the typical SiC MOSFET performance curves of the MSCSM170AM45CT1AG device.

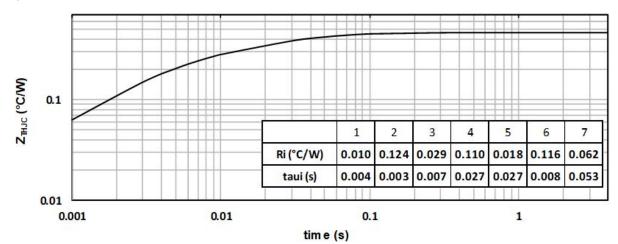


Figure 1-1. Maximum Thermal Impedance

Electrical Specifications

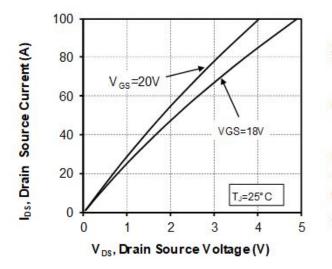
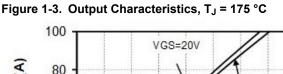
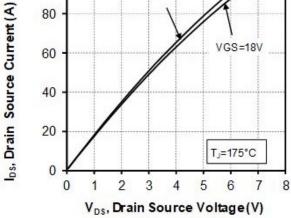
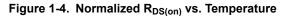


Figure 1-2. Output Characteristics, T_J = 25 °C







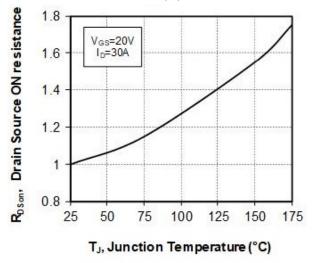
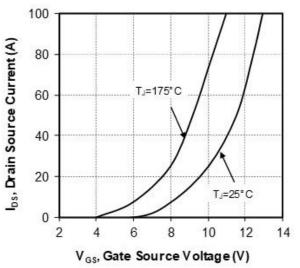
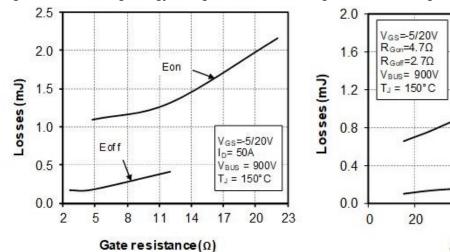
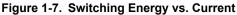


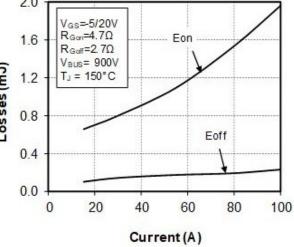
Figure 1-5. Transfer Characteristics



Electrical Specifications







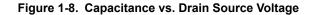
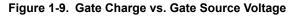
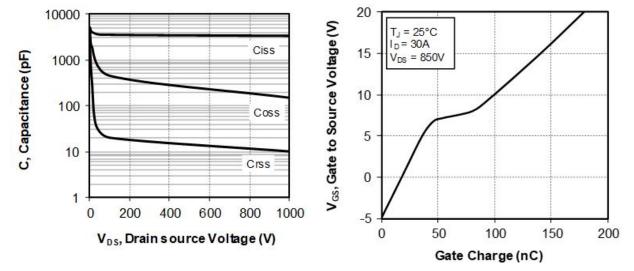


Figure 1-6. Switching Energy vs. Rg





Electrical Specifications

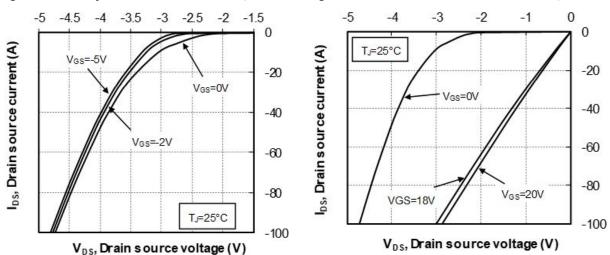


Figure 1-10. Body Diode Characteristics, $T_J = 25$ °C Figure 1-11. 3rd Quadrant Characteristics, $T_J = 25$ °C



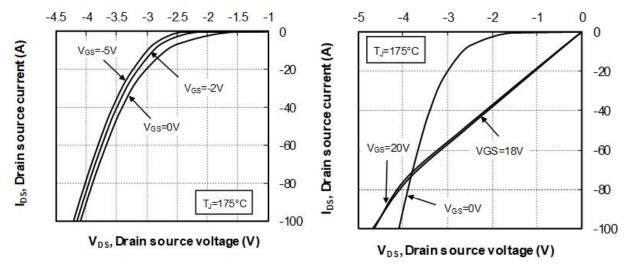
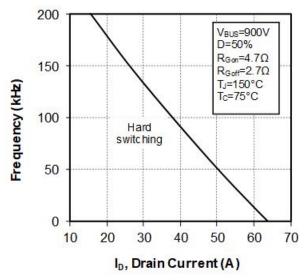


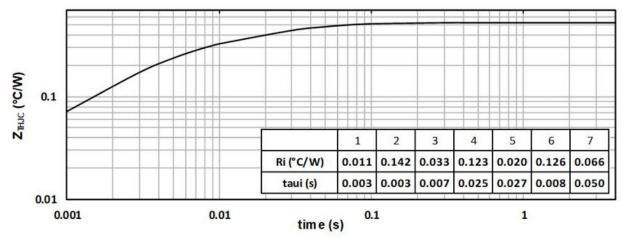
Figure 1-14. Operating Frequency vs Drain Current



1.5 Typical SiC Diode Performance Curves

This section shows the typical SiC diode performance curves of the MSCSM170AM45CT1AG device.





Electrical Specifications

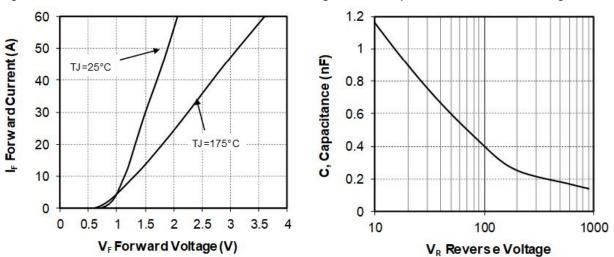


Figure 1-16. Forward Characteristics

Figure 1-17. Capacitance vs. Reverse Voltage

Package Specifications

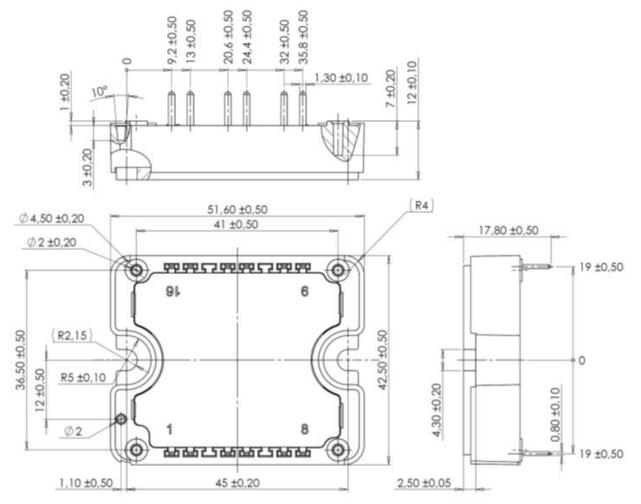
2. Package Specifications

The following section shows the package specification of the MSCSM170AM45CT1AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM170AM45CT1AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See AN3500A—Mounting Instructions for SP1F and SP3F Power Modules for more information.

3. Revision History

Revision	Date	Description
A	04/2021	This is the first publication of this document.

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